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10/617,667	07/14/2003	Jun Sumino	67161-068	4737	
20277 75	90 12/07/2005	EXAMINER			
MCDERMOTT WILL & EMERY LLP			PRENTY, MARK V		
600 13TH STRI WASHINGTON	EET, N.W. N, DC 20005-3096		ART UNIT	PAPER NUMBER	
·	,		2822		
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Please find below and/or attached an Office communication concerning this application or proceeding.

			Application No.		Applicant(s)	
Office Action Summary			10/617,667		SUMINO ET AL.	
		E	Examiner		Art Unit	
		N	MARK PRENTY		2822	
The MAILING Period for Reply	DATE of this communic	cation appea	rs on the cover shee	t with the co	rrespondence ad	idress
A SHORTENED ST WHICHEVER IS LC - Extensions of time may be after SIX (6) MONTHS fr - If NO period for reply is s - Failure to reply within the Any reply received by the	ATUTORY PERIOD FO DNGER, FROM THE MA e available under the provisions of orm the mailing date of this commu- pecified above, the maximum stat set or extended period for reply v Office later than three months af timent. See 37 CFR 1.704(b).	AILING DAT of 37 CFR 1.136(a unication. cutory period will a vill, by statute, ca	E OF THIS COMMU a). In no event, however, ma apply and will expire SIX (6) I use the application to becom	UNICATION. ay a reply be time MONTHS from the ne ABANDONED	ly filed ne mailing date of this c (35 U.S.C. § 133).	
Status						
2a)☐ This action is 3)☐ Since this ap	communication(s) filed FINAL. 2 Discation is in condition for	b)⊠ This ac or allowance	ction is non-final. e except for formal m	•		e merits is
Disposition of Claims						
4a) Of the abo 5)⊠ Claim(s) <u>1 an</u> 6)⊠ Claim(s) <u>9</u> is/ 7)□ Claim(s)	d 3-9 is/are pending in to a series of the claim (s) is/are d 3-8 is/are allowed. are rejected. is/are objected to. are subject to restrict	e withdrawn	from consideration.			
Application Papers						
10)☐ The drawing(s Applicant may Replacement c	ion is objected to by the) filed on is/are: not request that any objected to eclaration is objected to	a) accept tion to the dra the correction	awing(s) be held in abe	eyance. See wing(s) is obje	37 CFR 1.85(a). cted to. See 37 C	• •
Priority under 35 U.S.	C. § 119					
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	s Patent Drawing Review (PT Statement(s) (PTO-1449 or F		Paper			O-152)

Application/Control Number: 10/617,667

Art Unit: 2822

This Office Action is in response to the RCE filed on November 21, 2005.

Claim 9 is rejected under 35 U.S.C. 102(e) as being anticipated by United States Patent 6,620,681 to Kim et al. (Kim).

With respect to independent claim 9, Kim discloses a semiconductor device (see the entire reference, particularly the Figs. 2A-2I and Fig. 3 disclosure) comprising: a semiconductor substrate 100, having a main surface, in which first and second trenches 109 are formed in said main surface at a distance away from each other; first and second isolation insulating films 112 filling in said first and second trenches (see the Fig. 2E disclosure, and note that Figs. 2F-2I's elements 124 are composites of Fig. 2E's elements 110 and 112); a silicon-containing insulating film 101/102, formed on said main surface located between said first isolation insulating film and said second isolation insulating film, having an end portion in a bird's beak (Fig. 3's "a"); a silicon film 103/104 formed on said silicon-containing insulating film, having a thickness exceeding 0 and being less than 50 nm (see column 5, lines 52-55) in an intermediate portion between said first isolation insulating film and said second isolation insulating film, and being thinner than said thickness on said end portion (see Fig. 3); and sidewall insulating films 110 (see Figs. 2D-2E), formed between said silicon-containing insulating film 101/102 and each of said first and second insulating films 112 so as to [bring into] contact [with] the sidewalls of said silicon film 103/104 and said silicon-containing insulating film 101/102.

Claim 9 is thus rejected under 35 U.S.C. 102(e) as being anticipated by Kim.

Claims 1 and 3-8 are allowable over the prior art of record.

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United States Patent 6,933,194 is relevant to this application.

Registered practitioners can telephone the examiner at (571) 272-1843. Any voicemail message left for the examiner must include the name and registration number of the registered practitioner calling, and the Application/Control (Serial) Number. Technology Center 2800's general telephone number is (571) 272-2800.

Mark V. Prenty Primary Examiner/

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